Electronic Supplementary Material (ESI) for CrystEngComm. This journal is © The Royal Society of Chemistry 2021

Supporting Information

Growth mechanism on graphene-regulated high-quality epitaxy of flexible AlN film

Yanqing Jia, Haidi Wu, Jianglin Zhao, Haibin Guo, Yu Zeng, Boyu Wang, Chi Zhang, Yachao Zhang, Jing Ning *, Jincheng Zhang *, Tao Zhang*, Dong Wang, Yue Hao

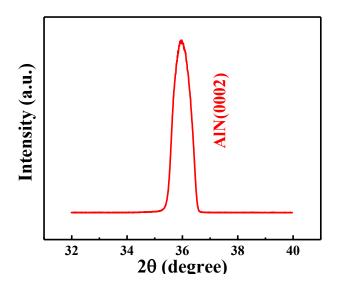


Figure S1. 2θ - ω scanning curve of AlN with growth time of 50 min.

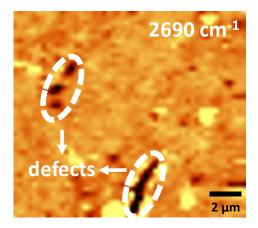


Figure S2. Raman mapping of 2D peak (2690 cm⁻¹) of graphene on sample after epitaxial growth.